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HMC573* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

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- HMC573LC3B Evaluation Board

Documentation

Data Sheet

- HMC573 Data Sheet

Tools and Simulations

- HMC573 S-Parameter

Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: LC3, LC3B, LC3C (QTR: 2014-00376 REV: 01)
- Semiconductor Qualification Test Report: PHEMT-F (QTR: 2013-00269)

Design Resources

- HMC573 Material Declaration
- PCN-PDN Information
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- Symbols and Footprints

Discussions

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Sample and Buy

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Technical Support

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SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 8 - 22 GHz OUTPUT

Typical Applications

The HMC573LC3B is suitable for:

- Clock Generation Applications: SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space

Features

High Output Power: +12 dBm

Low Input Power Drive: 0 to +6 dBm

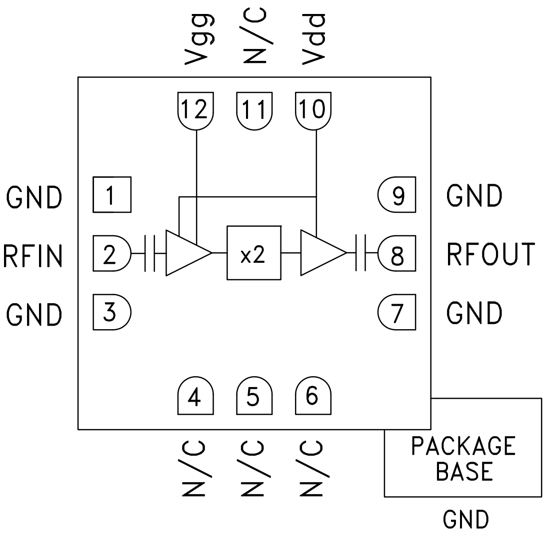
Fo Isolation: >20 dBc @ Fout= 16 GHz

100 KHz SSB Phase Noise: -134 dBc/Hz

Single Supply: +5V@ 92 mA

RoHS Compliant 3x3 mm SMT Package

Functional Diagram



General Description

The HMC573LC3B is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a leadless RoHS compliant SMT package. When driven by a +5 dBm signal, the multiplier provides +12 dBm typical output power from 8 to 22 GHz. The Fo and 3Fo isolations are >20 dBc and >25 dBc respectively at 16 GHz. The HMC573LC3B is ideal for use in LO multiplier chains for Pt-to-Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -134 dBc/Hz at 100 kHz offset helps maintain good system noise performance. The RoHS packaged HMC573LC3B eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

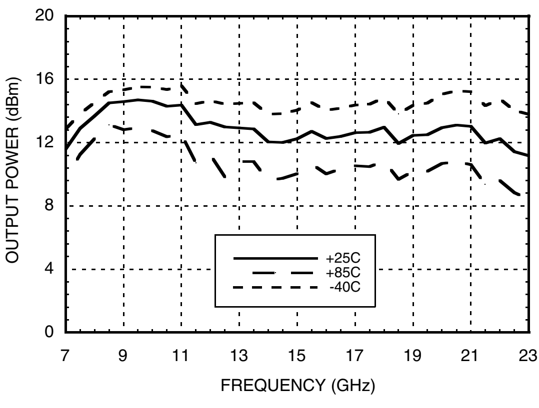
Electrical Specifications, T_A = +25°C, Vdd = +5V, 5 dBm Drive Level

Parameter	Min.	Typ.	Max.	Units
Frequency Range, Input		4 - 11		GHz
Frequency Range, Output		8 - 22		GHz
Output Power	9	12		dBm
Fo Isolation (with respect to output level)		20		dBc
3Fo Isolation (with respect to output level)		25		dBc
4Fo Isolation (with respect to output level)		15		dBc
Input Return Loss		10		dB
Output Return Loss		10		dB
SSB Phase Noise (100 kHz Offset)		-134		dBc/Hz
Supply Current (Idd) (Vdd = 5V, Vgg = -1.25V Typ.)		92		mA

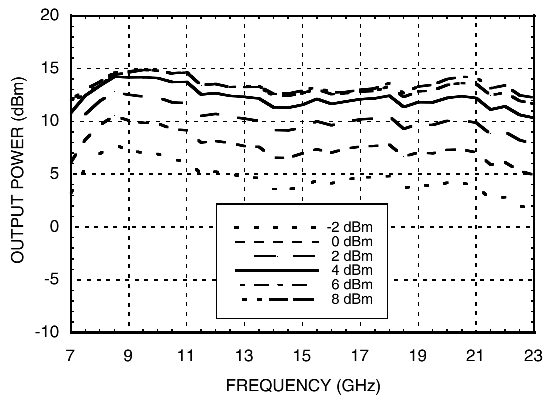
*Adjust Vgg between -1.5 and ~1.1V to achieve Idd = 92 mA

For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com
Application Support: Phone: 978-250-3343 or apps@hittite.com

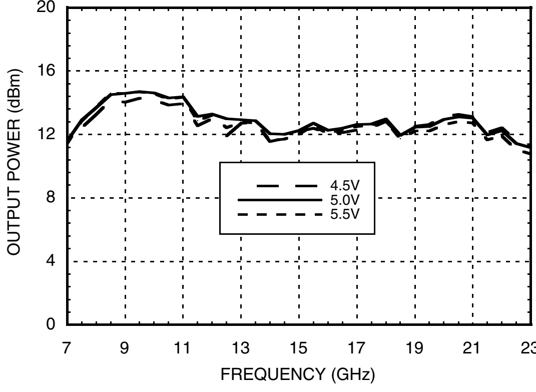
Output Power vs. Temperature @ 5 dBm Drive Level



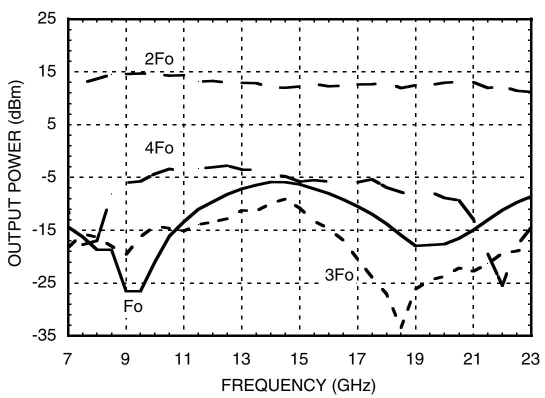
Output Power vs. Drive Level



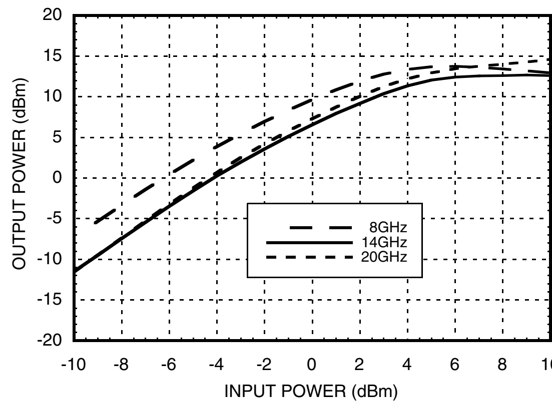
Output Power vs. Supply Voltage @ 5 dBm Drive Level



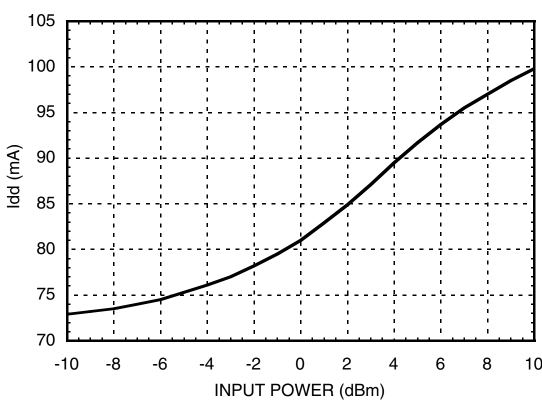
Isolation @ 5 dBm Drive Level



Output Power vs. Input Power

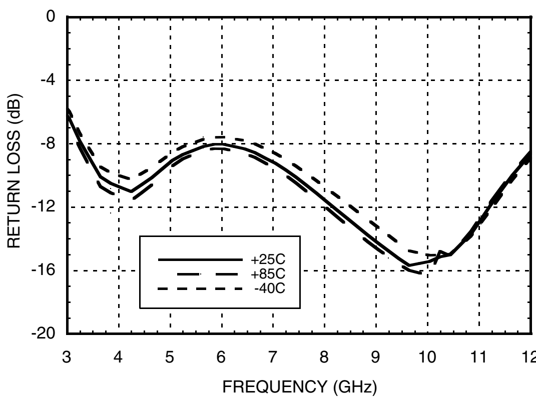


Supply Current vs. Input Power

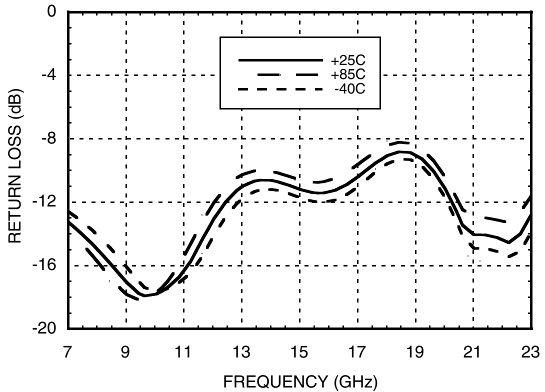


SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 8 - 22 GHz OUTPUT

Input Return Loss vs. Temperature



Output Return Loss vs. Temperature



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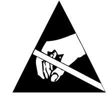
Absolute Maximum Ratings

RF Input (Vdd = +5V)	+10 dBm
Supply Voltage (Vdd)	+6.0 Vdc
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 8.0 mW/°C above 85 °C)	719 mW
Thermal Resistance (channel to ground paddle)	125 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Typical Supply Current vs. Vdd

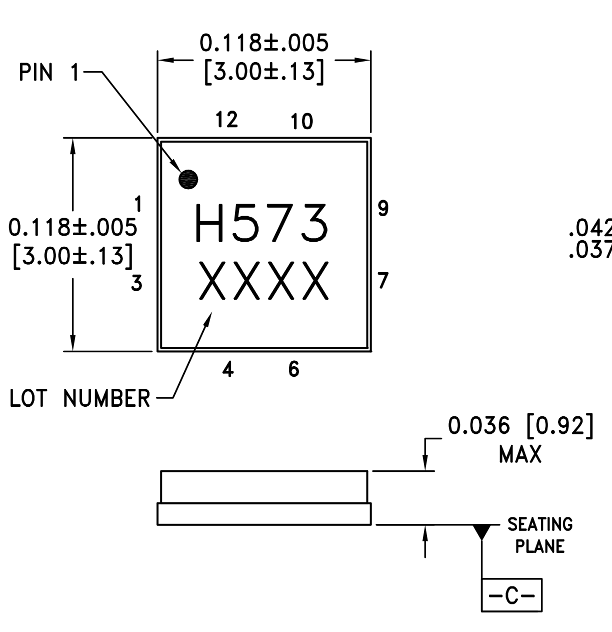
Vdd (Vdc)	Idd (mA)
4.5	90
5.0	92
5.5	94

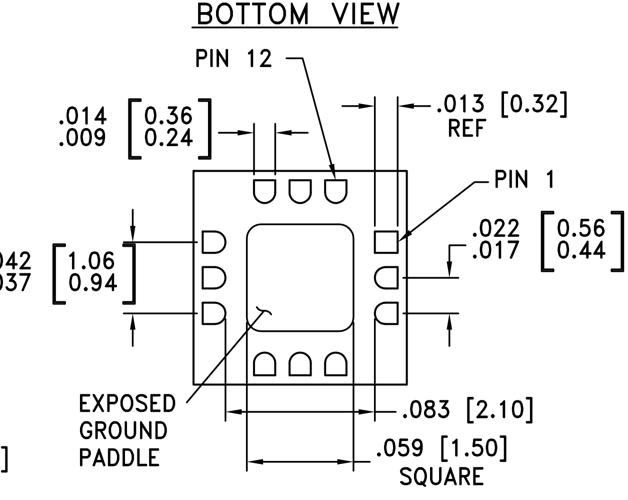
Note:
Multiplier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing





NOTES:
1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC573LC3B	Alumina, White	Gold over Nickel	MSL3 [1]	H573 XXXX

[1] Max peak reflow temperature of 260 °C
[2] 4-Digit lot number XXXX

Pin Description

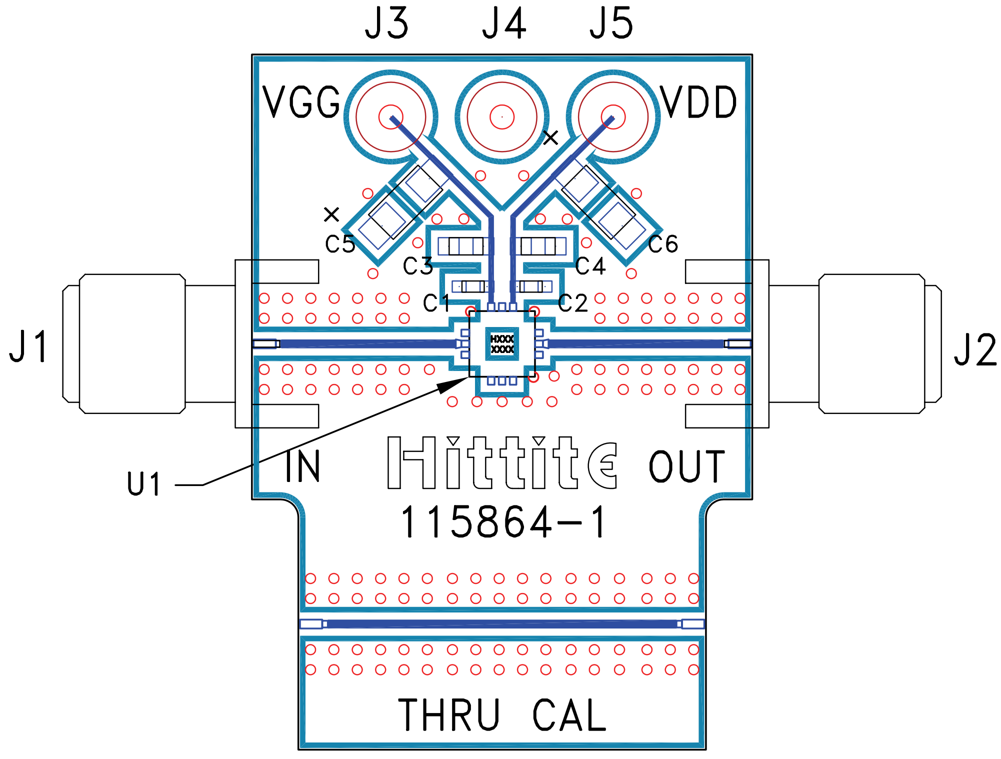
Pin Number	Function	Description	Interface Schematic
1, 3, 7, 9	GND	Package bottom must also be connected to RF/DC ground.	GND
2	RFIN	Pin is AC coupled and matched to 50 Ohms.	RFIN
4 - 6, 11	N/C	These pins are internally not connected; however, this product was specified with these pins connected to RF/ DC ground.	
8	RFOUT	Pin is AC coupled and matched to 50 Ohms.	RFOUT
10	Vdd	Supply voltage 5V ± 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 µF are required.	Vdd
12	Vgg	Gate control for amplifier. Adjust to achieve Idd of 92 mA. Please follow “MMIC Amplifier Biasing Procedure” Application note.	Vgg

Application Circuit

Component	Value
C1, C2	100 pF
C3, C4	1,000 pF
C5, C6	2.2 µF

J3 J5
C1 C3 C5 C2 C4 C6
12 10
Vgg Vdd
2 RFIN RFOUT 8
J1 J2
HMC573LC3B
1,3,7,9
J4

Evaluation PCB



List of Materials for Evaluation PCB 115739 [1]

Item	Description
J1, J2	PCB Mount SRI K Connector
J3 - J5	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	1,000 pF Capacitor, 0603 Pkg.
C5, C6	2.2 µF Tantalum Capacitor
U1	HMC573LC3B x2 Active Multiplier
PCB [2]	115864 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.